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# SEE test for ABCStar V0 at CSNS for ITk Strip Upgrade

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For China ATLAS ITk team

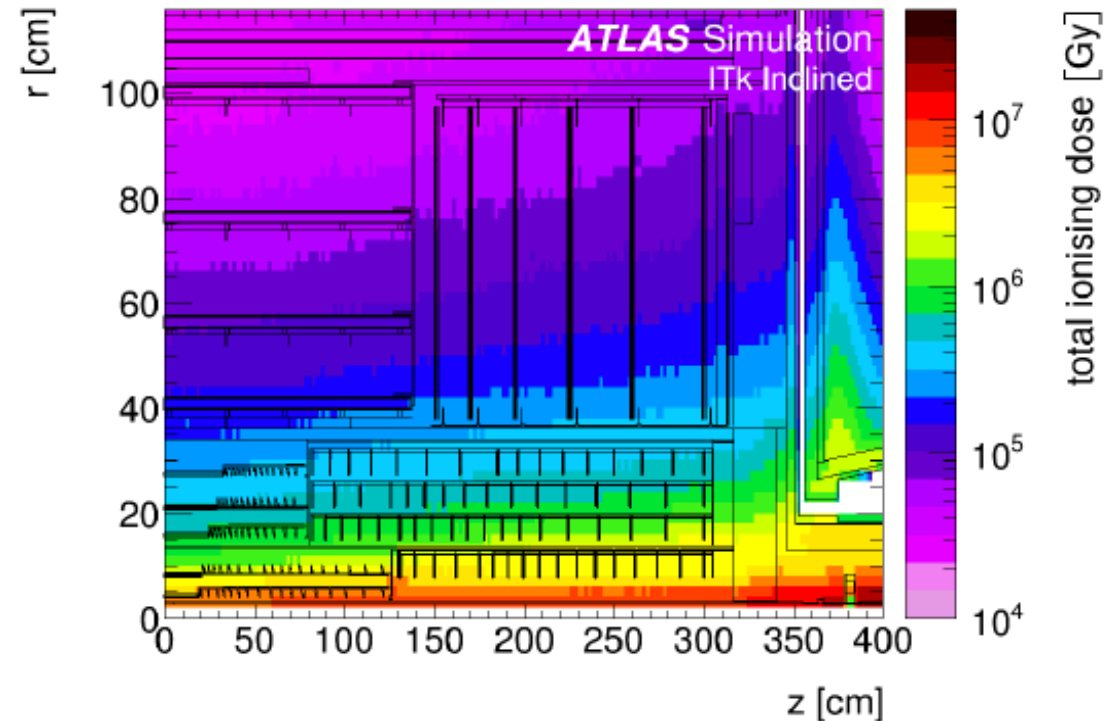
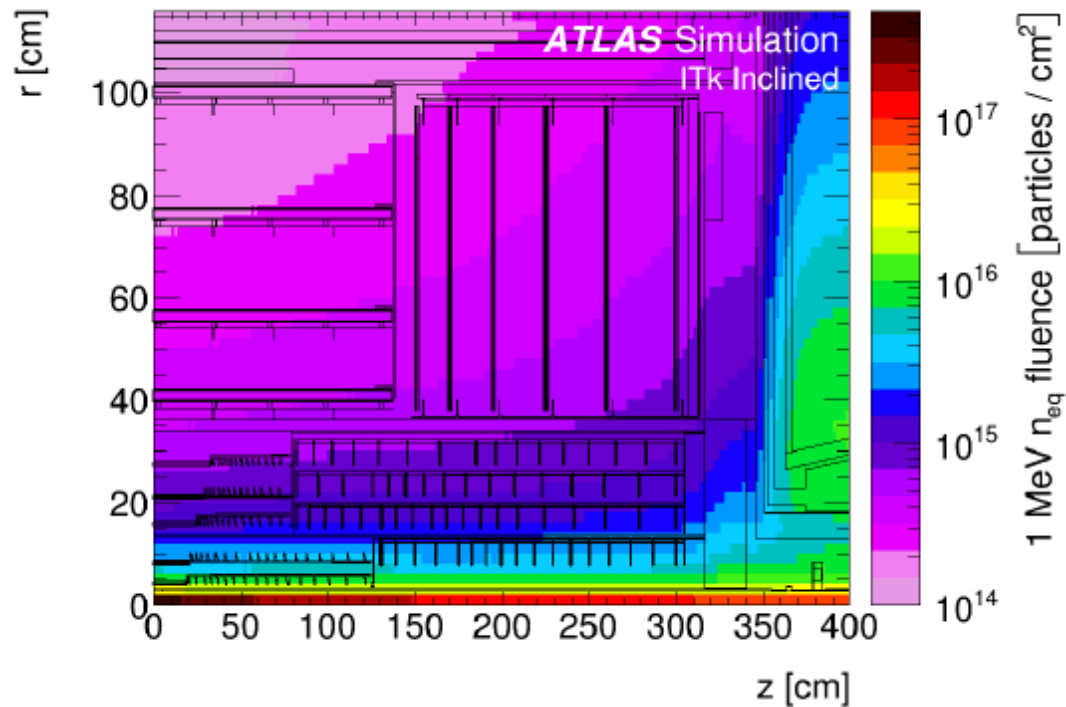
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# Outline

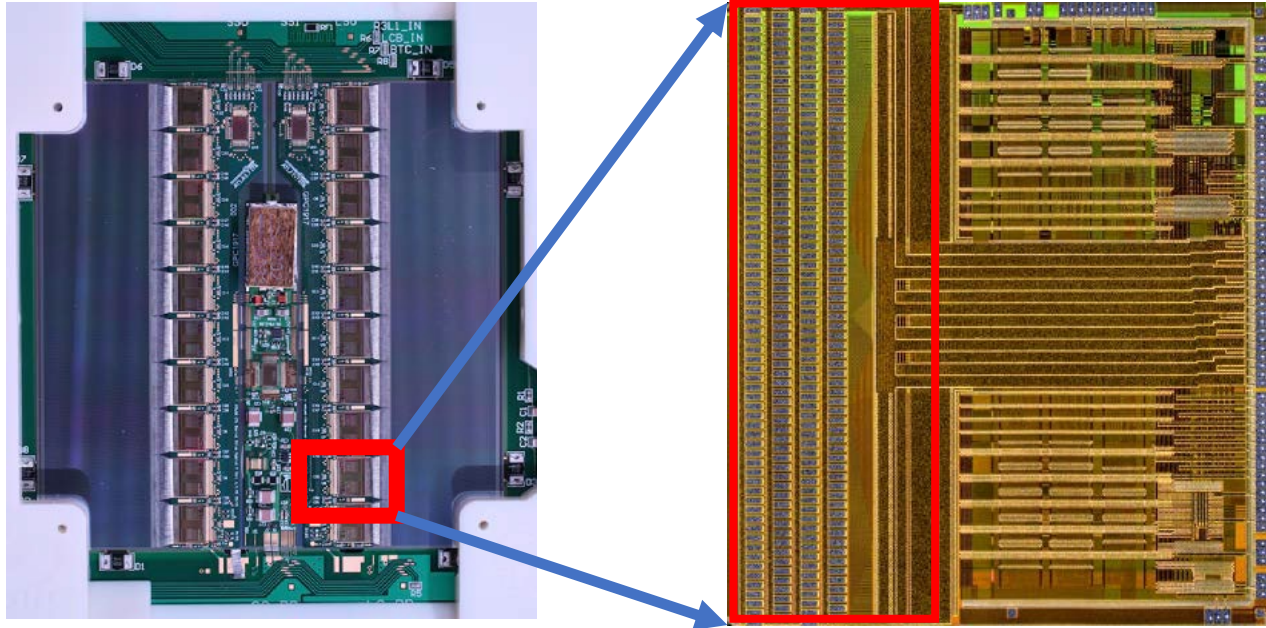
- ABCStar chips and radiation effect
- Data taking at CSNS
- Analysis results
- Summary

# Radiation environment in ITk

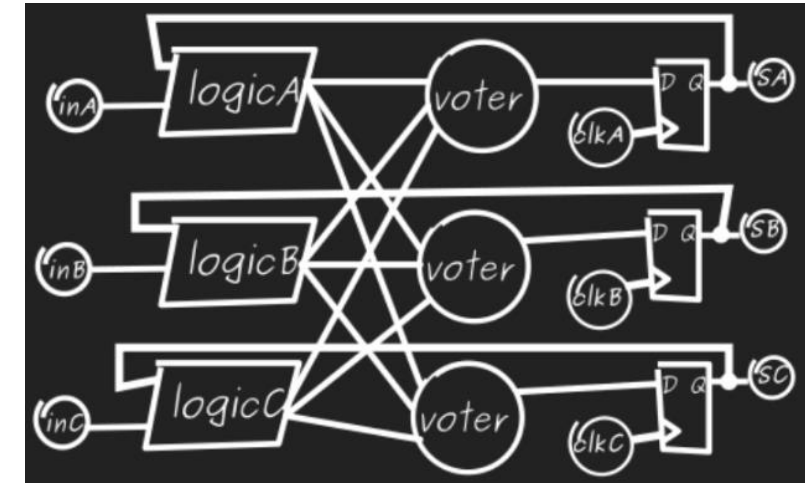
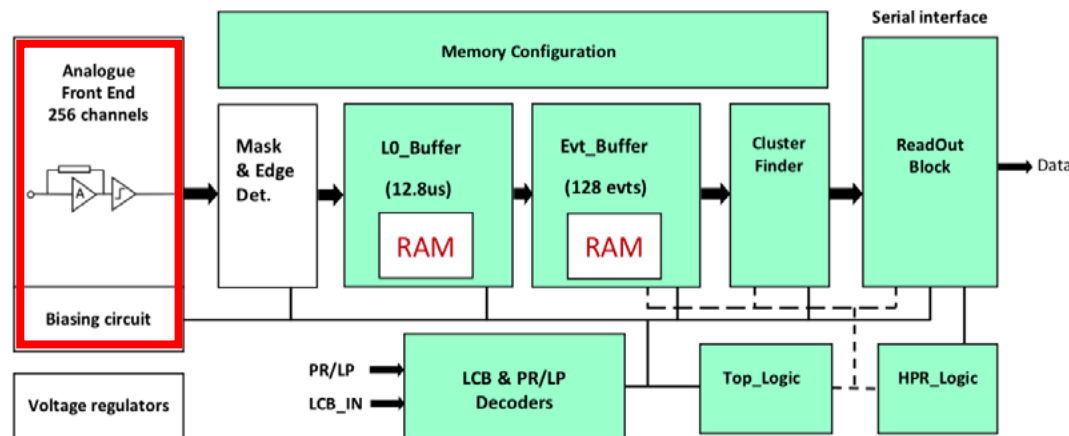
- The fluence and dose distributions for the ITk layout
  - NIEL:  $1.2 \times 10^{15} n_{eq}/cm^2$     TID: 50 MRad



# ABCStar chips



- front end readout ASIC for ATLAS ITk detector
- Key component of the ITk strip module, ~230,000 needed for production
- Process of signals from 256 silicon strips channel
- Two versions of design
  - V0
  - V1 (TMR protection)



**TMR**

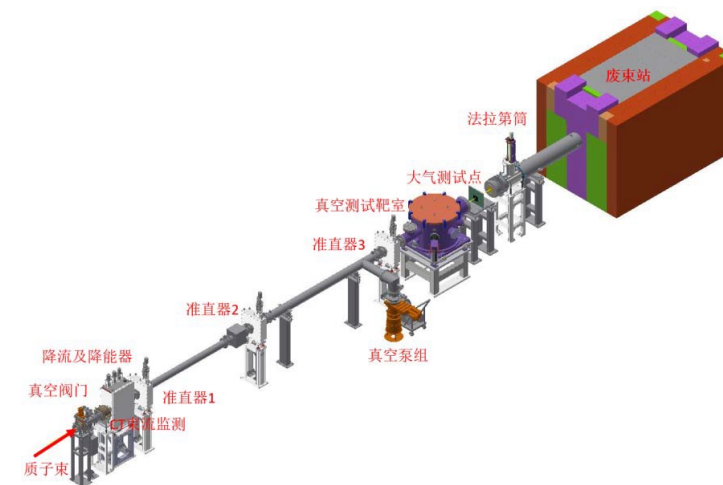
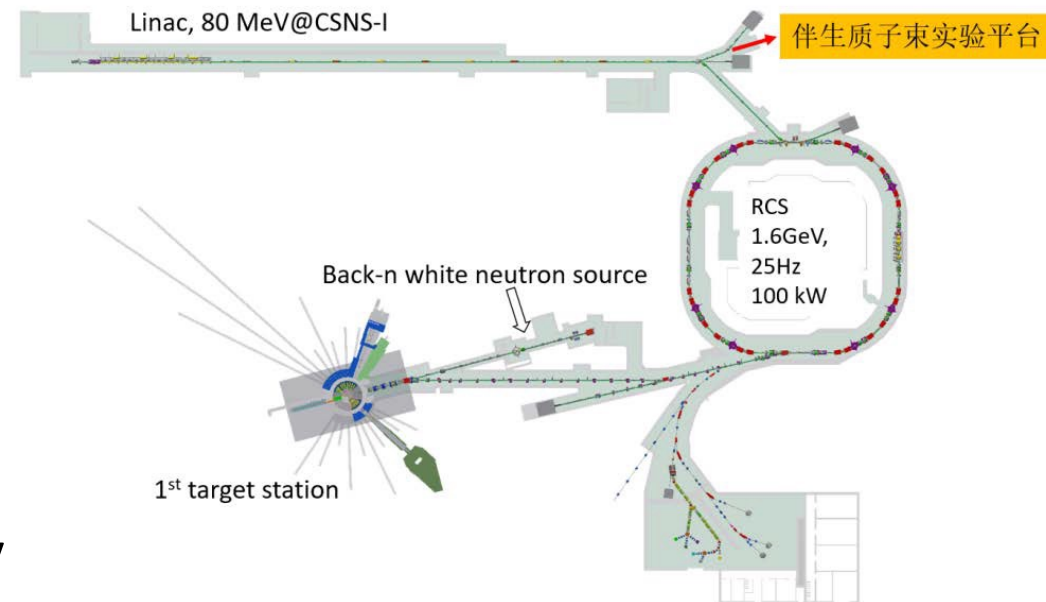
# Radiation effect in electronics

- Cumulative radiation effects
  - TID effects
  - Displacement damage
- Single-Event effects
  - Single event upsets
    - change of state in memory due to an electrical disturbance from radiation
  - result in wrong data and misconfiguration

Category	Type	comment
Non-destructive (soft errors)	SEU(Single -Event Upsets)	<ul style="list-style-type: none"><li>• Static upsets in storage cell such as SRAM, latches and flip-flops</li><li>• High Error rate can cause system degradation</li><li>• Correctable by reprogramming</li></ul>
	SET(Single- Event Transients)	Transient voltage perturbation for combinational logic
	SEFI(Single-Event Functional Interrupts)	
Destructive (hard errors)	SEL(Single-Event Latchup)	Recover from power cycle if current limiting functions embedded in design
	SEB(Single-Event Burnout)	Catastrophic failure in high voltage device
	SEGR(Single-Event Gate Rupture)	Permanent damage

# APEP at CSNS

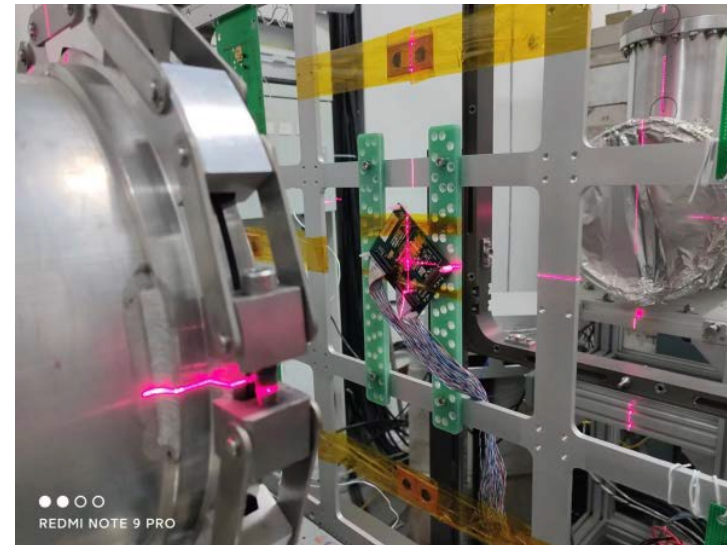
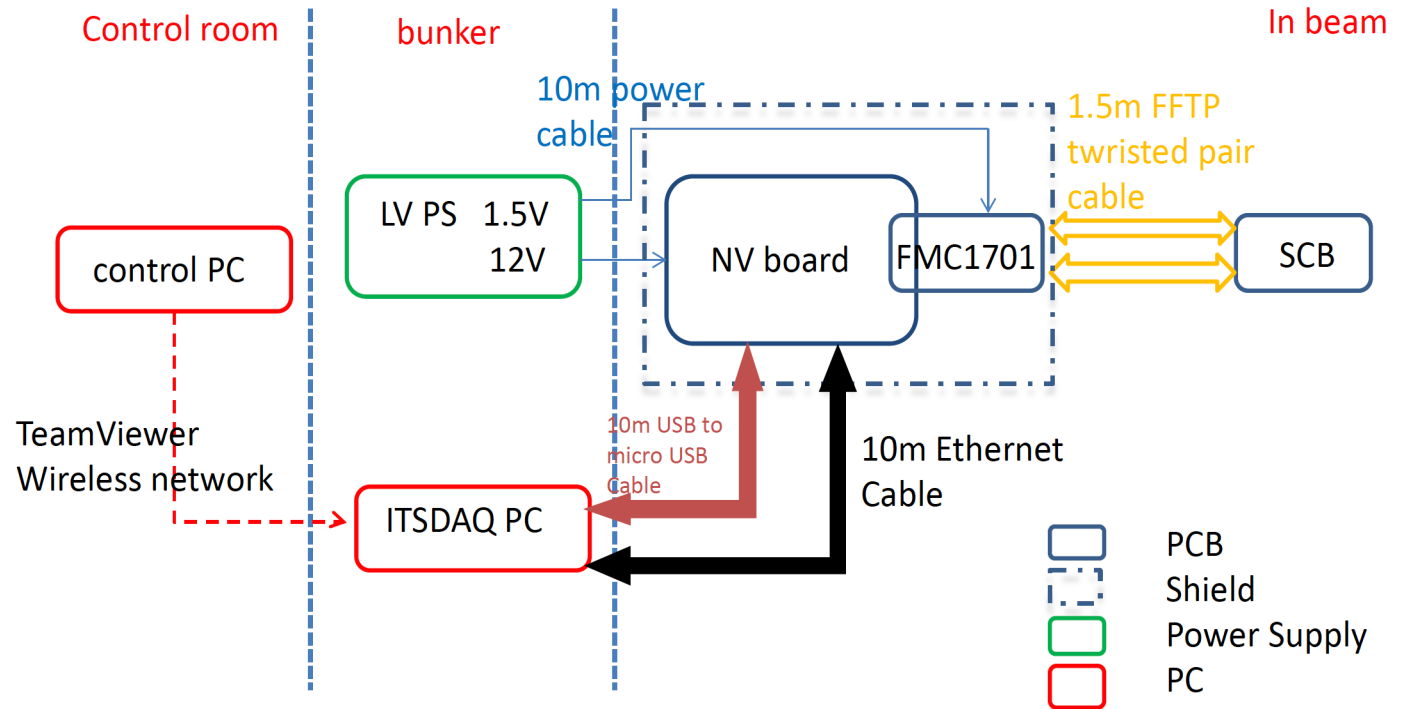
- CSNS: China Spallation Neutron Source
- APEP: Associated Proton Experiment Platform
- Beam parameter
  - Energy: 10-80MeV, FWHM < 8.65% @ >30MeV
  - Size: 10mm\*10mm-50mm\*50mm, continuous tuned square window
  - Flux:  $10^5$ - $10^{10}$  p/cm<sup>2</sup>/s
  - Height: 1.2m
  - Beam time: ~5000hrs/year
- TRIUMF team have performed the SEE exp already.





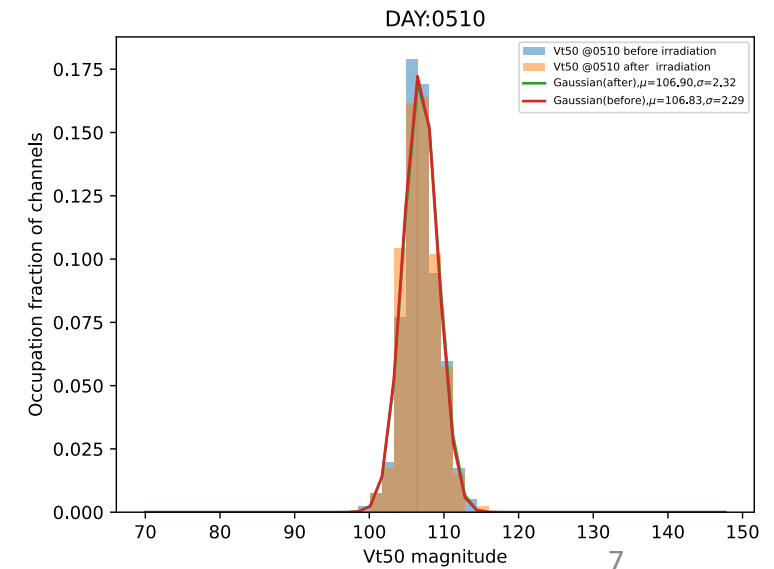
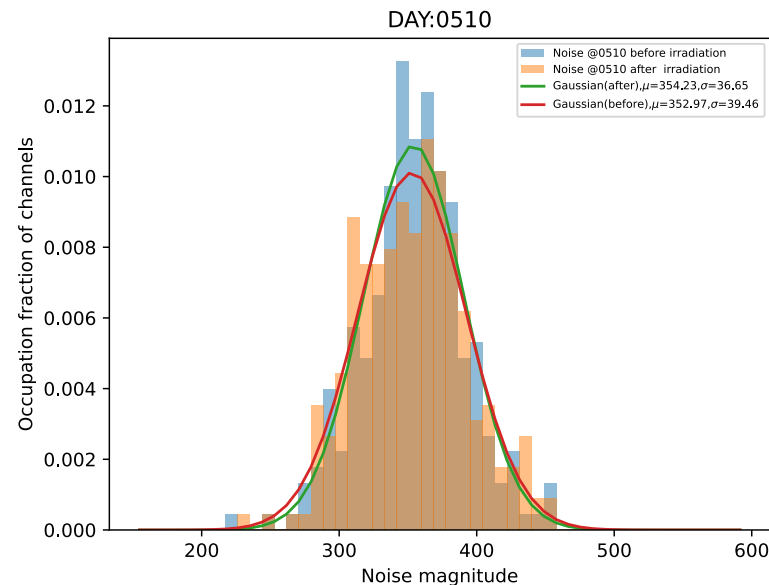
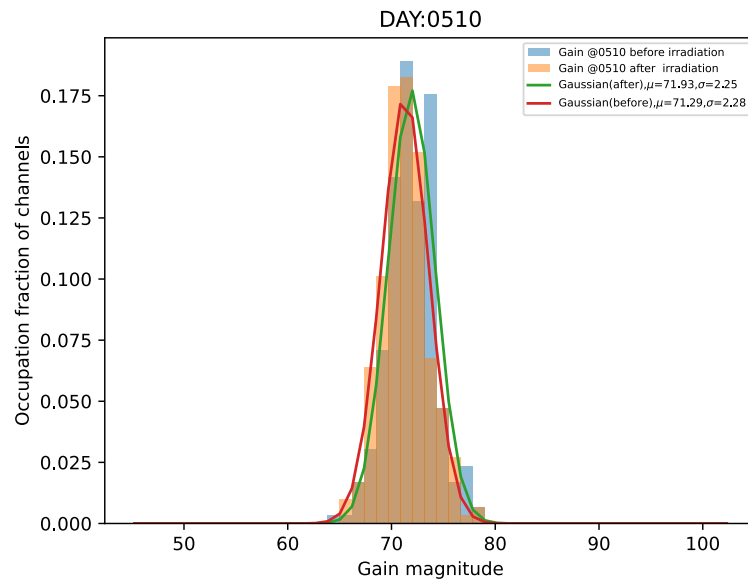
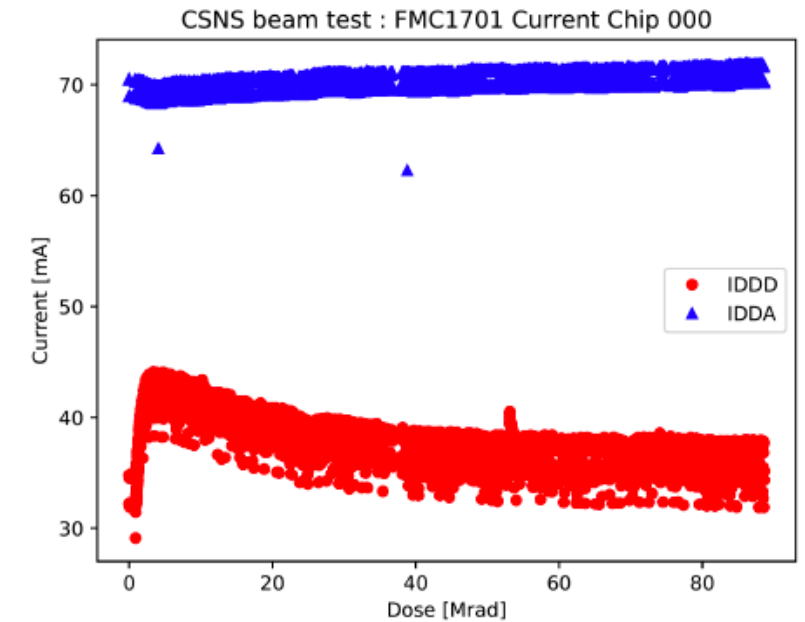
# Data taking

- Data taking
  - Taking procedure using scripts
    - Fixed pattern mode
    - ~1hr time block, 20 cycles
  - 3 time slots
    - ~37.5 hours
      - May-10, May-11
    - ~12 hours
      - May-13
    - ~14 hours
      - May-14



# Results— current and performance

- Current measurements
  - IDDA and IDDD vs total dose
  - Total dose up to 88 Mrad
  - Peak of TID bump at  $\sim 2$ Mrad
- Analog performance
  - No obvious difference observed before and after irradiation





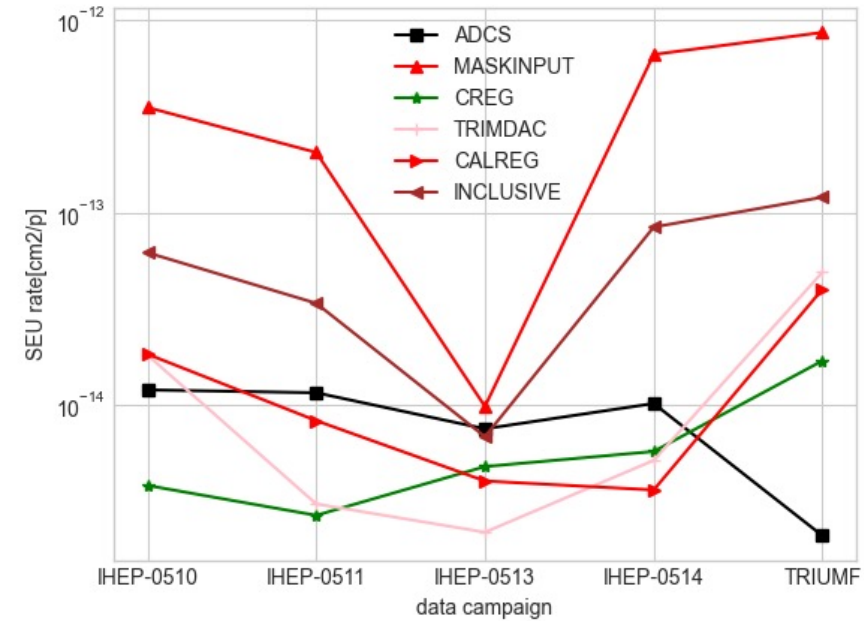
# Results– Physics packets

- $\sigma_{SEU} = \frac{n_{0 \rightarrow 1} + n_{1 \rightarrow 0}}{\int d\phi}$ 
  - $\int d\phi$ : total fluence
  - $n_{0 \rightarrow 1} / n_{1 \rightarrow 0}$ : bit flips
- the difference of two causes:
  - the number of SEM counts
  - the distance of the SCBs from the beampipe

Chip Type	Institute	Fill-type	$n_{0 \rightarrow 1}$	$n_{1 \rightarrow 0}$	N-bits	$\int d\phi [p/cm^2]$	$\sigma_{SEU} [cm^2/p]$
V0	IHEP	Fixed	1832293	119324	52153344	$3.1 \times 10^{17}$	$(6.3 \pm 0.08) \times 10^{-12}$
V0	TRIUMF	Fixed	33699	34546	15250176	$1.86 \times 10^{16}$	$(3.7 \pm 0.03) \times 10^{-12}$
V1	TRIUMF	Fixed	16343	16506	7462368	$4.47 \times 10^{15}$	$(7.4 \pm 0.08) \times 10^{-12}$

# Results– Register packets

- Mismatch of cross-section
- The potential causes:
  - Beam energy
    - 80MeV at CSNS
    - 480 MeV at TRIUMF
  - Fluence uncertainty
    - angle of incidence of beam through chips
- Synergistic Effects
  - Total ionizing dose on SEU



Register Type	Fill-type	Chip Type	Institute	$n_{1 \rightarrow 0}$	$n_{0 \rightarrow 1}$	N-bits	$\int d\phi [p/cm^2]$	$\sigma_{SEU} [cm^2/p]$
ADCS	Fixed	V0	TRIUMF/ IHEP	1/19	0/10	301792/ 1684608	$2.5 \times 10^{14} / 2.7 \times 10^{15}$	$2.1 \times 10^{-15} / 1.1 \times 10^{-14}$
MASKINPUT				281/336	1/768	402400/ 2246048	$3.3 \times 10^{14} / 3.7 \times 10^{15}$	$8.6 \times 10^{-13} / 3.0 \times 10^{-13}$
CERG				1/2	4/8	352096/ 1964736	$2.9 \times 10^{14} / 3.2 \times 10^{15}$	$1.7 \times 10^{-14} / 3.1 \times 10^{-15}$
TRIMDAC				82/131	1/1	2010592/ 11226080	$1.7 \times 10^{15} / 1.8 \times 10^{16}$	$4.9 \times 10^{-14} / 7.0 \times 10^{-15}$
CALREG				13/31	1/0	401856/ 2245056	$3.5 \times 10^{14} / 3.8 \times 10^{15}$	$4.0 \times 10^{-14} / 8.1 \times 10^{-15}$
INCLUSIVE				378/688	16/804	3518912/ 19647296	$3.2 \times 10^{15} / 3.2 \times 10^{16}$	$1.2 \times 10^{-13} / 4.6 \times 10^{-14}$

# Results– HPR reset and unlock rates

- High Priority Register packets
  - contain link status information
  - be sent at regular intervals
    - integer multiples of 40,000 BCs(1 ms)
    - Out-of-time packets used to detect the **resets** in ASIC
- LCB\_Locked bit(bit 29) in HPR packet to
  - identify the **unlocked** HPR packets

Chip Type	Institute	Fill-type	Unlocked rate(upper limit)	Out of time packets rate
V0	IHEP	Fixed	$9 \times 10^{-5}$	$5 \times 10^{-3}$
	TRIUMF		$1.65 \times 10^{-5}$	$9 \times 10^{-5}$

# Results– Register status bits

- The status bit for register read packets are checked
  - IHEP: 0.0005% for LP/PR FIFO
  - TRIUMF: 0.0007% for LP/PR FIFO
- Non zero Register and cluster FIFO indicate ASIC resets in IHEP experiments, which is consistent with the large out-of-time HPR packet rate.

Chip Type	Institute	Fill-type	PR_FIFO_almost_full	LP_FIFO_almost_full	RegFIFO	CLusterFIFO	Npackets
V0	IHEP	Fixed	148	147	277	288	28880406
	TRIUMF		159	228	0	0	22916647

# Results— Estimated impact on operation

- Typical HL-LHC parameters
  - pileup 200
  - BC rates 40MHz
  - $Rate_{SEU} = O(10^{-10})$  errors/event/ABCStar
- Error rate due to thermal noise occupancy:  $10^{-2}$  errors/event/ABCStar
- During the normal operation, the hit errors in physics packet clusters is  $20\text{ s}^{-1}$ , so there is **no practical concern**.

# Summary

- SEE test is critical for ABCStar under ITk strip environment
  - Successful data collection at CSNS APEP provides a new platform for SEE test with medium energy proton
  - More than 60 effective hrs data taking based on ABCStar V0 SEE test setup
- Data analysis has been done
  - The result is mostly consistent with that obtained from TRIUMF experiments.
  - Still need further test to check the specific causes.
- Perform SEE test for ITk Strip ASICs ABCStar V1 and other chips
  - check the TMR protection.

# Backup

- $\Phi_{hadrons} = O(10^7) \text{ hadrons/cm}^2/\text{s}$
- expected fluences  $O(10^{-3}) \text{ hadrons/cm}^2/\text{pp}$
- $Rate_{SEU} = \left( \Phi_{hadrons} \times \frac{\text{time in pipeline}}{\text{packet}} \right) \times \frac{\text{packets}}{\text{event}} \times \sigma_{SEU}$   
 $= O(10^7) \times O(10^{-5}) \times O(10^{-12})$   
 $= O(10^{-10}) \text{ errors/event/ABCStar}$

Effect of Total Ionizing Dose on  
SEUs for 0.25  $\mu\text{m}$  SRAM - change  
in SEU cross-section

